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() IDT.

DATASHEET

VERSACLOCK[®] LOW POWER CLOCK GENERATOR

IDT5P49EE805

Description

The IDT5P49EE805 is a programmable clock generator intended for low power, battery operated consumer applications. There are four internal PLLs, each individually programmable, allowing for four unique non-integer-related frequencies. The frequencies are generated from a single reference clock. The reference clock can come from either a TCXO or input clock. An additional 32kHz crystal oscillator is available to provide a real time clock or non-critical performance MHz processor clock.

Two buffered reference Sine wave output clock are supported with amplitude of 750 mV to 1V, peak to peak.

The IDT5P49EE805 can be programmed through the use of the l^2C interfaces. The programming interface enables the device to be programmed when it is in normal operation or what is commonly known as in system programmable. An internal EEPROM allows the user to save and restore the configuration of the device without having to reprogram it on power-up.

Each of the four PLLs has an 8-bit reference divider and a 11-bit feedback divider. This allows the user to generate four unique non-integer-related frequencies. The PLL loop bandwidth is programmable to allow the user to tailor the PLL response to the application. For instance, the user can tune the PLL parameters to minimize jitter generation or to maximize jitter attenuation. Spread spectrum generation is supported on one of the PLLs.

There are total six 8-bit output dividers. Outputs are LVCMOS. The outputs are connected to the PLLs via the switch matrix. The switch matrix allows the user to route the PLL outputs to any output bank. This feature can be used to simplify and optimize the board layout. In addition, each output's slew rate and enable/disable function can be programmed.

Target Applications

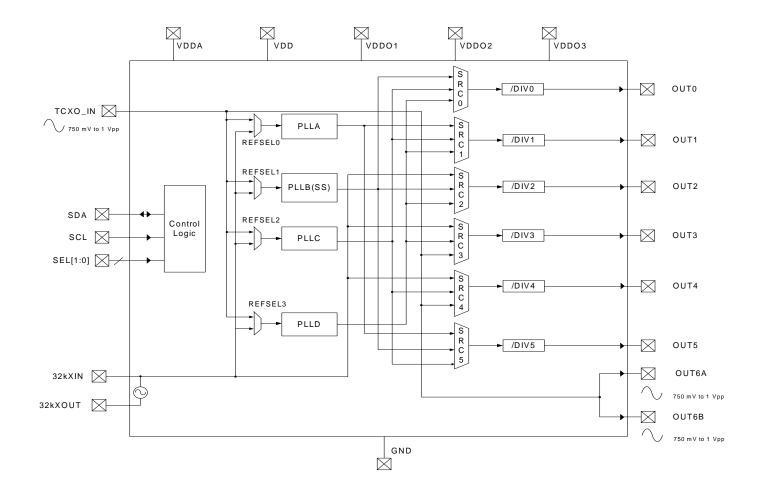
- Smart Mobile Handset
- Personal Navigation Device (PND)
- Camcorder
- DSC
- Portable Game Console
- Personal Media Player

Features

- Four internal PLLs
- Internal non-volatile EEPROM
 - Internal I²C EEPROM master interface
- FAST (400kHz) mode I²C serial interfaces
- Input Frequencies

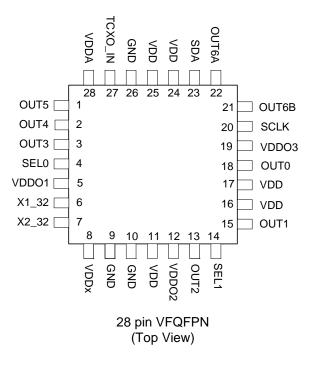
 TCXO: 10 MHz to 40 MHz
 RTC Crystal: 32.768 kHz
- Two buffered Sine wave outputs at 750 mV to 1Vpp
- Output Frequency Ranges: kHz to 100 MHz
- Each PLL has an 8-bit reference divider and a 11-bit feedback-divider
- 8-bit output-divider blocks
- One of the PLLs support Spread Spectrum generation capable of configuration to pixel rate, with adjustable modulation rate and amplitude to support video clock with no visible artifacts
- I/O Standards:
 - Outputs 1.8V/2.5V/3.3 V LVTTL/ LVCMOS
- 3 independent adjustable VDDO groups.
- Programmable Slew Rate Control
- Programmable Loop Bandwidth Settings
- · Programmable output inversion to reduce bimodal jitter
- Individual output enable/disable
- Power-down/Sleep mode
 - 10µA max in power down mode
 - 32kHz clock output active sleep mode
 - 100 $\!\mu A$ max in sleep mode
- 1.8V VDD Core Voltage
- Available in 28-pin 4x4mm QFN packages
- -40 to +85°C Industrial Temp operation

Functional Block Diagram



2

Pin Assignment



Pin Descriptions

Pin Name	Pin #	I/O	Pin Type	Pin Description	
OUT5	1	0	Adjustable	Configurable clock output 5. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
OUT4	2	0	Adjustable	Configurable clock output 4. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
OUT3	3	0	Adjustable	Configurable clock output 3. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
SEL0*	4	I	LVTTL	Configuration select pin. Weak internal pull down resistor.	
VDDO1	5		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT5. VDDO1 must be greater than or equal to both VDDO2 and VDDO3.	
X132k	6	I	LVTTL	TL 32kHz CRYSTAL_IN Reference crystal input	
X232k	7	0	LVTTL	32kHz CRYSTAL_OUT Reference crystal feedback.	
VDDx	8		Power	Crystal oscillator power supply. Connect to 1.8V. Use filtered analog power supply if available.	
GND	9		Power	Connect to Ground.	
GND	10		Power	Connect to Ground.	
VDD	11		Power	Device power supply. Connect to 1.8V.	
VDDO2	12		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT5.	
OUT2	13	0	Adjustable	Configurable clock output 2. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
SEL1*	14	Ι	LVTTL	Configuration select pin. Weak internal pull down resistor.	

Pin Name	Pin #	I/O	Pin Type	Pin Description	
OUT1	15	0	Adjustable	Configurable clock output 1. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
VDD	16		Power	Device power supply. Connect to 1.8V.	
VDD	17		Power	Device power supply. Connect to 1.8V.	
OUT0	18	0	Adjustable	Configurable clock output 0. Single-ended output voltage levels are register controlled by either VDDO1, VDDO2 or VDDO3.	
VDDO3	19		Power	Device power supply. Connect to 1.8 to 3.3V. Using register settings, select output voltage levels for OUT0-OUT5.	
SCLK	20		LVTTL	I ² C clock. Logic levels set by VDDO1. 5V tolerant.	
OUT6B	21	0	Output	Buffered reference Sine wave clock output. Single-ended output voltage levels are controlled by VDDA. Output high-Z when disabled. AC couple wiht $0.1\mu F$ capacitor.	
OUT6A	22	0	Output	Buffered reference Sine wave clock output. Single-ended output voltage levels are controlled by VDDA. Output high-Z when disabled. AC couple wiht $0.1\mu F$ capacitor.	
SDA	23	I/O	Open Drain	Bidirectional I ² C data. Logic levels set by VDDO1. 5V tolerant.	
VDD	24		Power	Device power supply. Connect to 1.8V.	
VDD	25		Power	Device power supply. Connect to 1.8V.	
GND	26		Power	Connect to Ground.	
TCXO_IN	27	Ι	Input	TCXO clock input.	
VDDA	28		Power	Filtered analog power supply. Connect to 1.8V.	

Note *: SEL pins should be controlled by 1.8V LVTTL logic; 3.3V tolerant.

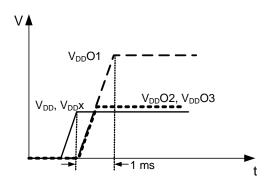
Note 1: Outputs are user programmable to drive single-ended 1.8V/2.5V/3.3V LVTTL. Differential LVDS interface levels can be generated for OUT4A/OUT4B when connected to VDDO1=3.3V and registers configured appropriately. Alway completely power up VDD and VDDx prior to applying VDDO power.

Note 2: Default configuration CLK1=Buffered MHz Reference output and CLK2=Buffered 32.768kHz output. All other outputs are off.

Note 3: Do not power up with SEL[1:0] = 00 (in Power down/Sleep mode).

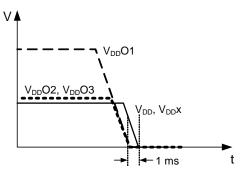
Ideal Power Up Sequence

- 1) V_{DD} and $V_{DD}x$ must come up first, followed by $V_{DD}O$
- 2) V_{DD}O1 must come up within 1ms after VDD and VDDX come up
- 3) $V_{DD}O2/3$ must be equal to, or lower than, $V_{DD}O1$
- 4) V_{DD} and $V_{DD}x$ have approx. the same ramp rate
- 5) V_{DD}O1 and V_{DD}O2/3 have approx. same ramp rate

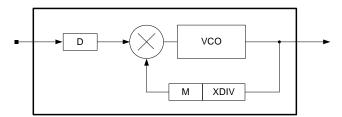


Ideal Power Down Sequence

- 1) $V_{DD}O$ must drop first, followed by V_{DD} and $V_{DD}x$
- 2) V_{DD} and V_{DD}x must come down within 1ms after V_{DD}O1 comes down
- 3) $V_{DD}O2/3$ must be equal to, or lower than, $V_{DD}O1$
- 4) V_{DD} and $V_{DD}x$ have approx. the same ramp rate
- 5) $V_{DD}O1$ and $V_{DD}O2/3$ have approx. same ramp rate



PLL Features and Descriptions



PLL Block Diagram

	Ref-Divider (D) Values	Feedback Pre-Divider (XDIV) Values	Feedback (M) Values	Programmable Loop Bandwidth	Spread Spectrum Generation Capability
PLLA	1 - 255	1 or 4	6 - 2047	Yes	No
PLLB	1 - 255	4	6 - 2047	Yes	Yes
PLLC	1 - 255	1 or 8 bit divide	6 - 2047	Yes	No
PLLD	1 - 255	1 or 4	6 - 2047	Yes	No

Crystal Input (XIN/REF)

The crystal oscillators should be fundamental mode quartz crystals; overtone crystals are not suitable. Crystal frequency should be specified for parallel resonance with 50Ω maximum equivalent series resonance. 0

ONXTALB=0 bit needs to be set for XIN/REF.

Crystal Load Capacitors

The device crystal connections should include pads for small capacitors from X1 to ground and from X2 to ground. These capacitors are used to adjust the stray capacitance of the board to match the nominally required crystal load capacitance. Because load capacitance can only be increased in this trimming process, it is important to keep stray capacitance to a minimum by using very short PCB traces (and no vias) between the crystal and device. Crystal capacitors must be connected from each of the pins X1 and X2 to ground.

The crystal cpacitors are internal to the device and have an effective value of 4pF.

Reference Pre-Divider, Reference Divider, Feedback-Divider and Post-Divider

Each PLL incorporates an 8-bit reference-scaler and a 11-bit feedback divider which allows the user to generate four unique non-integer-related frequencies. PLLA and PLLD each have a feedback pre-divider that provides additional multiplication for kHz reference clock applications. Each output divider supports 8-bit post-divider. The following equation governs how the output frequency is calculated.

$$F_{OUT} = \frac{F_{IN} * \left(\frac{XDIV*M}{D}\right)}{ODIV} (Eq. 2)$$

Where F_{IN} is the reference frequency, XDIV is the feedback pre-divider value, M is the feedback-divider value, D is the reference divider value, ODIV is the total post-divider value, and F_{OUT} is the resulting output frequency. Programming any of the dividers may cause glitches on the outputs.

SPREAD SPECTRUM GENERATION (PLLB)

PLLB has spread spectrum generation capability, which users have the option of turning on and off. Spread spectrum profile, frequency, and spread are fully programmable (within limits). The programmable spread spectrum generation parameters are NC[10:0], MOD[12:0], and NSS[10:0] bits. To enable spread spectrum, set SSENB_B=0.

The spread spectrum circuitry was specifically developed to accommodate video display applications. The spread modulation frequency can be defined to exactly equal the horizontal line frequency (HSYNC)

NC[10:0]

These bits are used to determine the number of pulses per spread spectrum cycle. For video applications, NC is the number of pixels on the horizontal display row (or integer multiple of displayed pixels in a row). By matching the spread period to the screen, no tearing or "shimmer" will be apparent.

NC must be an even number to insure that the upward spread transition has the same number of steps as the downward spread transition.

For non-video applications, this can also be seen as the number of clock cycles for a complete spread spectrum period.

MOD[12:0]

These bits relate the reference frequency to the target average spread output frequency (F_{MID}). F_{MID} is the midpoint between F_{MAX} (maximum frequency) and F_{MIN} (minimum frequency).

 $F_{MID} = (F_{MAX} + F_{MIN}) / 2$

 $MOD = (F_{REF} * NC) / (2 * F_{MID})$

NSS[10:0]

These bits control the amplitude of the spread modulation.

 $NSS = (NC / 2) + (NC / 8) * (F_{MAX} - F_{MIN}) / F_{MID}$

Modulation frequency:

 $F_{MOD} = F_{MID} / NC (Eq. 11)$

Video Example

 $F_{REF} = 25MHz$, $F_{OUT} = 27$ MHz, 640 pixels per line, center spread of ±1%. Find the necessary spread spectrum register settings.

 $F_{MID} = F_{OUT}$

NC = 640 or 320 or 160 (integer number of spread periods/screen)

MOD = (25MHz * 640)/(2 * 27MHz) = 296

NSS = (640/2)+(640/8)*(27.27MHz-26.73MHz)/27MHz = 322.

 $F_{MOD} = 27MHz/640 = 42.2kHz.$

Non-Video Example

 F_{REF} = 25MHz, F_{OUT} = 27 MHz, 32kHz modulation rate, center spread of ±1%. Find the necessary spread spectrum register settings.

 $F_{MID} = F_{OUT}$

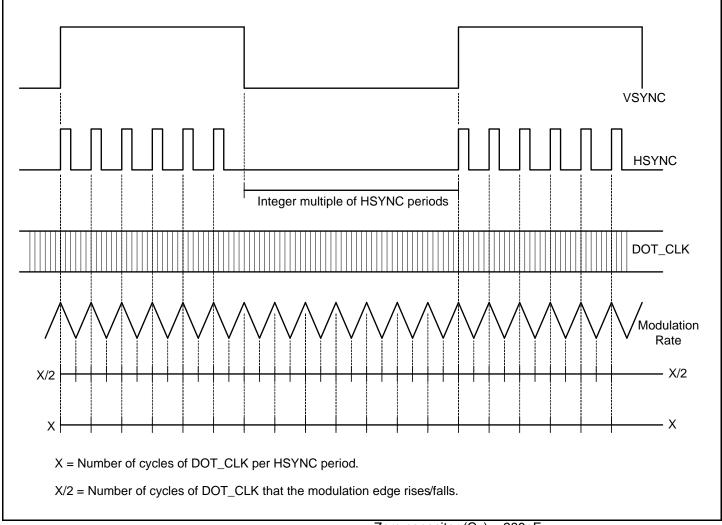
 $F_{MOD} = 32$ kHz = 27MHz/NC.

NC = 844

MOD = (25MHz * 844)/(2 * 27MHz) = 391

NSS = (844/2)+(844/8)*(27.27MHz-26.73MHz)/27MHz = 424.

VSYNC, HSYNC, DOT_CLK – Modulation Rate Relationship



LOOP FILTER

The loop filter for each PLL can be programmed to optimize the jitter performance. The low-pass frequency response of the PLL is the mechanism that dictates the jitter transfer characteristics. The loop bandwidth can be extracted from the jitter transfer. A narrow loop bandwidth is good for jitter attenuation while a wide loop bandwidth is best for low jitter generation. The specific loop filter components that can be programmed are the resistor via the RZ[4:0] bits, zero capacitor via the CZ[2:0] bits, pole capacitor via the CP[1:0] bits, and the charge pump current via the IP#[2:0] bits.

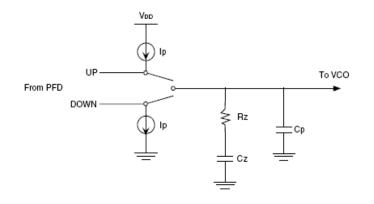
The following equations govern how the loop filter is set:

Zero capacitor (Cz) = 280pF

Pole capacitor (Cp) = 30pF

Charge pump (Ip) = IP#[2:0] uA

VCO gain (Kvco) = 350MHz/V * 2π



PLL Loop Bandwidth:

Charge pump gain $(K\phi) = Ip / 2\pi$

VCO gain (Kvco) = 350MHz/V * 2π

M = Total multiplier value (See the PRE-SCALERS, FEEDBACK-DIVIDERS, POST-DIVIDERS section for more detail)

$$\omega c = (Rz * K\phi * Kvco * Cz)/(M * (Cz + Cp))$$

 $Fc = \omega c / 2\pi$

Note, the phase/frequency detector frequency (FPFD) is typically seven times the PLL closed-loop bandwidth (Fc) but too high of a ratio will reduce your phase margin thus compromising loop stability.

To determine if the loop is stable, the phase margin (ϕ m) would need to be calculated as follows.

Phase Margin:

 $\omega z = 1 / (Rz * Cz)$

 $\alpha p = (Cz + Cp)/(Rz * Cz * Cp)$

 $\phi m = (360 / 2\pi) * [tan^{-1}(\omega c / \omega z) - tan^{-1}(\omega c / \omega p)]$

To ensure stability in the loop, the phase margin is recommended to be > 60° but too high will result in the lock time being excessively long. Certain loop filter parameters would need to be compromised to not only meet a required loop bandwidth but to also maintain loop stability.

Damping Factor:

 $\zeta = Rz/2 * (Kvco * Ip * Cz)^{1/2}/M$

Example

Fc = 150KHz is the desired loop bandwidth. The total A*M value is 160. The ζ (damping factor) target should be 0.7, meaning the loop is critically damped. Given Fc and A*M, an optimal loop filter setting needs to be solved for that will meet both the PLL loop bandwidth and maintain loop stability.

Choose a mid-range charge pump from register table

lcp= 11.9uA.

Ko * Kvco = 350MHz/V * 40uA = 12000A/Vs

 $\omega c = 2\pi * Fc = 9.42 \times 10^{5} \, s^{-1}$

 $\omega p = (Cz + Cp)/(Rz * Cz * Cp) = \omega z (1 + Cz / Cp)$

Solving for Rz, the best possible value Rz=30kOhms (RZ[1:0]=10) gives

 ζ = 1.4 (Ideal range for ζ is 0.7 to 1.4)

Solving back for the PLL loop bandwidth, Fc=149kHz.

The phase margin must be checked for loop stability.

 $\phi m = (360 / 2\pi) * [tan_1 (9.42x10^5 s^{-1} / 1.19x10^5 s^{-1}) - tan^{-1} (9.42x10^5 s^{-1} / 1.23x10^6 s^{-1})] = 45^{\circ}$

The phase margin would be acceptable with a fairly stable loop.

SEL[1:0] Function

The IDT5P49EE805 can support up to three unique configurations. Users may pre-program all configurations, selected using SEL[1:0] pins. Alternatively, users may use I2C interface to configure these registers on- the-fly.

Always power with SEL1=1 and/or SEL0=1.

SEL1	SEL0	Configuration Selections
0	0	Power Down/Sleep Mode
0	1	Select CONFIG0
1	0	Select CONFIG1
1	1	Select CONFIG2

Configuration OUTx IO Standard

Users can configure the individual output IO standard from

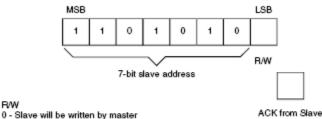
Programming the Device

I²C may be used to program the IDT5P49EE805.

- Device (slave) address = 7'b1101010

I²C Programming

The IDT5P49EE805 is programmed through an I²C-Bus serial interface, and is an I²C slave device. The read and write transfer formats are supported. The first byte of data after a write frame to the correct slave address is interpreted as the register address; this address auto-increments after each byte written or read.



1 - Slave will be read by master

R/W

The first byte transmitted by the Master is the Slave Address followed by the R/W bit. The Slave acknowledges by sending a "1" bit.

First Byte Transmitted on I²C Bus

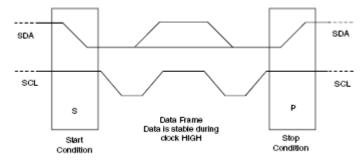
a single 3.3V power supply. Each output can support 1.8V/ 2.5V or 3.3V LVCMOS. VDDO1 must have the highest voltage of any pin on the device. VDDO2 and VDDO3 may have any value between 1.8V and VDDO1.

Power Down/Sleep Mode is selected by the No PD bit.

No PD=0 enables Power Down mode with no outputs.

No PD=1 enables sleep mode with 32kHz output on OUT2.

The frame formats are shown in the following illustration.



Framing

External I²C Interface Condition

KEY:

From Master to Slave

From Master to Slave, but can be omitted if followed by the correct sequence

Normally data transfer is terminated by a STOP condition generated by the Master. However, if the Master still wishes to communicate on the bus, it can generate a repeated START condition, and address another Slave address without first generating a STOP condition.

From Slave to Master

SYMBOLS:

ACK - Acknowledge (SDA LOW) NACK - Not Acknowledge (SDA HIGH) Sr - Repeated Start Condition S - START Condition

P-STOP Condition

EEPROM Interface

The IDT5P49EE805 can store its configuration in an internal EEPROM. The contents of the device's internal programming registers can be saved to the EEPROM by issuing a save instruction (ProgSave) and can be loaded back to the internal programming registers by issuing a restore instruction (ProgRestore).

To initiate a save or restore using I^2C , only two bytes are transferred. The Device Address is issued with the read/write bit set to "0", followed by the appropriate command code. The save or restore instruction executes

after the STOP condition is issued by the Master, during which time the IDT5P49EE805 will not generate Acknowledge bits. The IDT5P49EE805 will acknowledge the instructions after it has completed execution of them. During that time, the I^2C bus should be interpreted as busy by all other users of the bus.

On power-up of the IDT5P49EE805, an automatic restore is performed to load the EEPROM contents into the internal programming registers. The IDT5P49EE805 will be ready to accept a programming instruction once it acknowledges its 7-bit I²C address.

Progwrite

s	Address	R/W	ACK	Command Code	ACK	Register	ACK	Data	ACK	Р
	7-bits	0	1-bit	8-bits: xxxxxx00	1-bit	8-bits	1-bit	8-bits	1-bit	

Progwrite Command Frame

Writes can continue as long as a Stop condition is not sent and each byte will increment the register address.

Progread

Note: If the expected read command is not from the next higher register to the previous read or write command, then set a known "read" register address prior to a read operation by issuing the following command:

s	Address	R/W	ACK	Command Code	ACK	Register	АСК	$\overline{\mathscr{A}}$
	7-bits	0	1-bit	8-bits: xxxxxx00	1-bit	8-bits	1-bit	\square

Prior to Progread Command Set Register Address

The user can ignore the STOP condition above and use a repeated START condition instead, straight after the slave acknowledgement bit (i.e., followed by the Progread command):

S	Address	R/W	ACK	ID Byte	ACK	Data_1	ACK	Data_2	ACK	Data_last	NACK	Ρ
	7-bits	1	1-bit	8-bits	1-bit	8-bits	1-bit	8-bits	1-bit	8-bits	1-bit	

Progread Command Frame

Progsave

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx01	1-bit	

Note:

PROGWRITE is for writing to the IDT5P49EE805 registers. PROGREAD is for reading the IDT5P49EE805 registers. PROGSAVE is for saving all the contents of the IDT5P49EE805 registers to the EEPROM. PROGRESTORE is for loading the entire EEPROM contents to the IDT5P49EE805 registers.

Progrestore

s	Address	R/W	ACK	Command Code	ACK	Р
	7-bits	0	1-bit	8-bits:xxxxxx10	1-bit	

Note:

During PROGRESTORE, outputs will be turned off to ensure that no improper voltage levels are experienced before initialization.

I²C Bus DC Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{IH}	Input HIGH Level		0.7xVDDO1		5.5	V
V _{IL}	Input LOW Level				0.3xVDDO1	V
V _{HYS}	Hysteresis of Inputs		0.05xVDDO1			V
I _{IN}	Input Leakage Current	$V_{DD} = 0V$			±1.0	μA
V _{OL}	Output LOW Voltage	I _{OL} = 3 mA			0.4	V

I²C Bus AC Characteristics for Standard Mode

Symbol	Parameter	Min	Тур	Max	Unit
F _{SCLK}	Serial Clock Frequency (SCL)	0		100	kHz
t _{BUF}	Bus free time between STOP and START	4.7			μs
t _{SU:START}	Setup Time, START	4.7			μs
t _{HD:START}	Hold Time, START	4			μs
t _{SU:DATA}	Setup Time, data input (SDA)	250			ns
t _{HD:DATA}	Hold Time, data input (SDA) ¹	0			μs
t _{OVD}	Output data valid from clock			3.45	μs
CB	Capacitive Load for Each Bus Line			400	pF
t _R	Rise Time, data and clock (SDA, SCLK)			1000	ns
t _F	Fall Time, data and clock (SDA, SCLK)			300	ns
t _{HIGH}	HIGH Time, clock (SCLK)	4			μs
t _{LOW}	LOW Time, clock (SCLK)	4.7			μs
t _{SU:STOP}	Setup Time, STOP	4			μs

Note 1: A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the $V_{IH}MIN$ of the SCLK signal) to bridge the undefined region of the falling edge of SCLK.

I²C Bus AC Characteristics for Fast Mode

Symbol	Parameter	Min	Тур	Max	Unit
F _{SCLK}	Serial Clock Frequency (SCL)	0		400	kHz
t _{BUF}	Bus free time between STOP and START	1.3			μs
t _{SU:START}	Setup Time, START	0.6			μs
t _{HD:START}	Hold Time, START	0.6			μs
t _{SU:DATA}	Setup Time, data input (SDA)	100			ns
t _{HD:DATA}	Hold Time, data input (SDA) ¹	0			μs
t _{OVD}	Output data valid from clock			0.9	μs
CB	Capacitive Load for Each Bus Line			400	pF
t _R	Rise Time, data and clock (SDA, SCL)	20 + 0.1xC _B		300	ns
t _F	Fall Time, data and clock (SDA, SCL)	20 + 0.1xC _B		300	ns
t _{HIGH}	HIGH Time, clock (SCL)	0.6			μs
t _{LOW}	LOW Time, clock (SCL)	1.3			μs
t _{SU:STOP}	Setup Time, STOP	0.6			μs

Note 1: A device must internally provide a hold time of at least 300 ns for the SDA signal (referred to the $V_{IH}MIN$ of the SCL signal) to bridge the undefined region of the falling edge of SCL.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the IDT5P49EE805. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Symbol	Description	Мах	Unit
V _{DD}	Internal Power Supply Voltage	-0.5 to +4.6	V
VI	Input Voltage	-0.5 to +4.6	V
Vo	Output Voltage (not to exceed 4.6 V)	-0.5 to V _{DD} +0.5	V
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 to +150	°C

Recommended Operation Conditions

Symbol	Parameter	Min	Тур	Max	Unit
V _{DD} , V _{DD} x, V _{DD} A	Power supply voltage for core VDD	1.71	1.8	1.89	V
V _{DDOX}	Power supply voltage for outputs VDDO1/2/3	1.71	1.8	1.89	V
		2.375	2.5	2.625	V
		3.135	3.3	3.465	V
Τ _Α	Operating temperature, ambient	-40		+85	°C
C _{LOAD_OUT}	Maximum load capacitance (3.3V LVTTL only)			15	pF
C _{LOAD_OUT}	Maximum load capacitance (1.8V or 2.5V LVTTL only)			8	pF
F _{IN}	External reference clock TCXO_IN	10		40	MHz
t _{PU}	Power up time for all $V_{\text{DD}}\text{s}$ to reach minimum specified voltage (power ramps must be monotonic)	0.05		5	ms

Capacitance ($T_A = +25 \text{ °C}, f = 1 \text{ MHz}, V_{IN} = 0V$)

Symbol	Parameter	Min	Тур	Max	Unit					
C _{IN}	Input Capacitance		3		pF					
TCXO Specific	TCXO Specifications									
TCXO_FREQ	TCXO frequency	10		40	MHz					
TCXO_V _{PP}	Voltage swing (peak-to-peak, nominal)	0.75		1.0	V					

DC Electrical Characteristics for 3.3 Volt LVTTL¹

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = 33mA	2.4		VDDO	V
V _{OL}	Output LOW Voltage	I _{OH} = 33mA			0.4	V
I _{OZDD}	Output Leakage Current	3-state outputs			5	μA

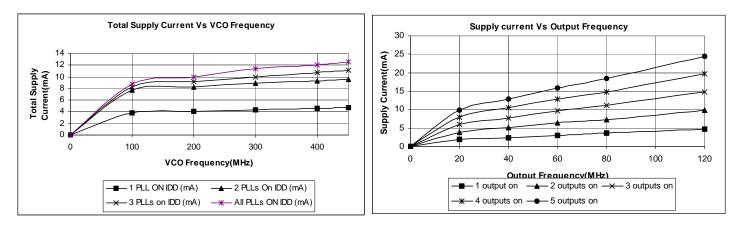
DC Electrical Characteristics for 2.5Volt LVTTL¹

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = 25mA	2.1		VDDO	V
V _{OL}	Output LOW Voltage	I _{OH} = 25mA			0.4	V
I _{OZDD}	Output Leakage Current	3-state outputs			5	μA

DC Electrical Characteristics for 1.8Volt LVTTL¹

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
V _{OH}	Output HIGH Voltage	I _{OH} = 18mA	0.65*VDDO		VDDO	V
V _{OL}	Output LOW Voltage	I _{OH} = 18mA			0.35*VDDO	V
V _{IH}	Input HIGH Voltage	SEL[1:0], 3.3V tolerant	0.75VDD			V
V _{IL}	Input LOW Voltage	SEL[1:0], 3.3V tolerant			0.25VDD	V
I _{OZDD}	Output Leakage Current	3-state outputs			5	μA

Power Supply Characteristics for LVTTL Outputs



Note 1: See "Recommended Operating Conditions" table. Alway completely power up VDD and VDDx prior to applying VDDO power.

AC Timing Electrical Characteristics

(Spread Spectrum Generation = OFF)

Symbol	Parameter Test Conditions		Min.	Тур.	Max.	Units
1 / t1	Output Frequency	Single Ended Clock output limit (LVTTL) 3.3V	0.001		100	MHz
		Single Ended Clock output limit (LVTTL) 2.5V	-		100	MHz
		Single Ended Clock output limit (LVTTL) 1.8V	-		100	MHz
f _{VCO}	VCO Frequency	VCO operating Frequency Range	100		500	MHz
f _{PFD}	PFD Frequency	PFD operating Frequency Range	0.5 ¹		100	MHz
f_{BW}	Loop Bandwidth	Based on loop filter resistor and capacitor values	0.01		10	MHz
t2	Input Duty Cycle	Duty Cycle for Input	40		60	%
t3	Output Duty Cycle	Measured at VDD/2	45		55	%
	Output Level - Vpp	OUT6A and OUT6B	0.75		1	Vpp
t4	Slew Rate, SLEWx(bits) = 00	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		5.1		V/ns
	Slew Rate, SLEWx(bits) = 01	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		4.4		
	Slew Rate, SLEWx(bits) = 10	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD (Output Load = 7 pF)		2.8		-
	Slew Rate, SLEWx(bits) = 11	Single-Ended 3.3V LVCMOS Output clock rise and fall time, 20% to 80% of VDD Output Load = 7 pF)		1.8		_
t5	Clock Jitter	Peak-to-peak period jitter, CLK outputs measured at VDD/2; f _{PFD} >= 10 MHz Single output frequency only.			100	ps
		Peak-to-peak period jitter, CLK outputs measured at VDD/2; f _{PFD} >= 10 MHz Multiple output frequencies switching.			200	ps
t6	Output Skew	Skew between output to output on the same bank			75	ps
		Skew between any output (Same freq and IO type, FOUT >10MHz)			200	ps
t7	Lock Time	PLL Lock Time from Power-up (using MHz reference clock) ¹		5	20	ms
		PLL Lock Time from Power-up using 32.768kHz reference clock)		1	3	S
		PLL Lock time from shutdown mode		5	10	ms

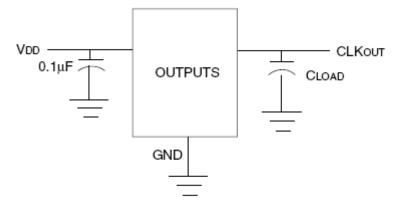
1.Time from supply voltage crosses VDD=1.62V to PLLs are locked.

Spread Spectrum Generation Specifications

Symbol	Parameter	Description	Min	Тур	Max	Unit
f _{IN}	Input Frequency	Input Frequency Limit	10		40	MHz
f _{MOD}	Mod Frequency	Modulation Frequency	32		120	kHz
f _{SPREAD}	Spread Value	Amount of Spread Value (programmable) - Down Spread	Pro	gramm	able	%f _{OUT}
		Amount of Spread Value (programmable) - Center Spread	Pro	gramm	able	

Note 1: Practical lower frequency is determined by loop filter settings.

Test Circuits and Conditions¹

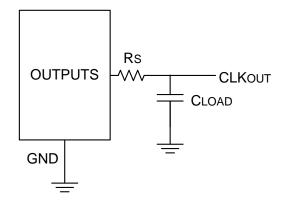


NOTE:

1. All Voo pins must be tied together.



Other Termination Scheme (Block Diagram)



Total load capacitance = 7pF

Programming Registers Table

	Default									
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x00	00	Reserved	CSX2	2[1:0]	CSX1	[1:0]	XTAL32ONB	Re	served	CSX2 [1:0]- internal 32kHz crystal cap2 00 - 18pF; 10 - 30pF 01 - 24pF; 11 - 36pF CSX1 [1:0] - Internal 32kHz crystal cap1 00 - 0pF; 10 - 6pF 01 - 3pF; 11 - 9pF XTAL32ONB - 32k crystal active low
0x01	00	INV[0]	SLEW	/0[0:1]	No_PD	P	S0[2:1]	Re	eserved	No_PD - Enables/Disables 32kHz
0x02	00	1			Res	erved				clock output on Config 00.
0x03	00	INV[1]	SLEW	/1[0:1]	Reserved	P	S12:1]	Re	eserved	No_PD=0 - 32kHz is off. No_PD=1 - 32kHz remains active.
0x04	00	INV[2]	SLEW	/20:1]	Reserved	P	S2[2:1]	Re	eserved	INV[#] - Invert output#
0x05	00	1			Res	erved				SLEW#[0:1] - output# slew setting 0 0 - 5.1V/ns
0x06	00	INV[3]	SLEW	/3[0:1]	Reserved	P	S3[2:1]	Re	eserved	0 0 - 5.1 V/IIS 0 1 - 4.4V/ns
0x07	00	INV[4]	SLEW	/4[0:1]	Reserved	Р	S42:1]	Reserved		1 0 - 2.8V/ns
0x08	00	INV[5]	SLEW	/5[0:1]	Reserved	P	S5[2:1]			1 1 - 1.8V/ns PS#[2:1] -Power Select
0x09	00				Res	erved				00 - Reserved 01 - CLK# connects to VDDO1 10 - CLK# connects to VDDO2 11 - CLK# connects to VDDO3
0x0A	00				Res	erved				
0x0B	00				Res	erved				
0x0C	00				Res	erved				
0x0D	00				Res	erved				
0x0E	00				REF	A[7:0]				Configuration0 REFA[7:0] - Reference Divide PLLA
0x0F	00				FBA	[10:3)				FBA[10:0] - Feedback Divide PLLA
0x10	00			Reserved				FBA[2:0)		
0x11	00	Reser	ved	R;	ZA[1:0]		IPA[2:0]	0] REFSELA		RZA[1:0] - Zero Resistor PLLA 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPA[2:0] - charge Pump Current PLLA 100 - 6.3uA 101 - 11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELA - Clock input PLLA 0 - MHz input 1 - 32kHz input
0x12	00			1	REF	B[7:0]				REFB[7:0] - Reference Divide PLLB
0x13	00					[10:3]				FBB[10:0] - Feedback Divide PLLB
0x14	00			MOD[4:0]				FBB[2:0]		PLLB Spread Parameters MOD[12:0]
0x15	00				MOD	0[12:5]		[0]		NC[10:0]
0x16	00					10:3]				NSS[12:0]
0x17	00			NSS[4:0]				NC[2:0]		
0x18	00				NSS	[12:5]				
5710					Nee	1 0]				

IDT5P49EE805 VERSACLOCK[®] LOW POWER CLOCK GENERATOR

	Default					Bit #				
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x19 0x1A	40 00		Reserved	Res	erved	IPB[2:0]		REFSELB	B[1:0] SSENB_B	RZB[1:0] - Zero Resistor PLLB 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPB[2:0] - charge Pump Current PLLB 000 - 0.37uA, 100 - 6.3uA 001 - 1.1uA, 101 - 11.9uA 010 - 1.8 uA, 110 - 17.7uA 011 - 3.4uA, 111 - 22.7uA REFSELB - Clock input PLLB 0 - MHZ input
0x1B	00					EFC[7:0]				REFC[7:0] - Reference Divide PLLC
0x1C	00				FE	3C[10:3]	1			FBC[10:0] - Feedback Divide PLLC
0x1D	00			Reserved				FBC[2:0]		
0x1E	00				FE	3C2[7:0]				FBC2 - Feedback Predivide PLLC Turn on using XDIVC=1
0x1F	00		IPC[2:0]		RZ	C[1:0]	Reserved	XDIVC	REFSELC	RZC[1:0] - Zero Resistor PLLC 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPC[2:0] - charge Pump Current PLLC 100 - 6.3uA 101 - 11.9 uA 110 - 27.7 uA 111 - 22.7uA REFSELC 0 - MHz input 1 - 32kHz input
0x20	00				RE	EFD[7:0]				REFD[7:0] - Reference Divide PLLD
0x21	00				FE	3D[10:3]				FBD[10:0] - Feedback Divide PLLD
0x22	00			Reserved				FBD[2:0]		
0x23	00	Reserved		D[1:0]		IPD[2:0]		ner3	ELD[1:0]	RZD[1:0] - Zero Resistor PLLD 00 - 5kOhm 01 - 10kOhm 10 - 30kOhm 11 - 80kOhm IPD[2:0] - charge Pump Current PLLD 100 - 6.3uA 101 - 11.9 uA 110 - 17.7 uA 111 - 22.7uA REFSELD[1:0] 00 - MHz input 11 - 32kHz input Others - Reserved
0x24	00					D0[7:0]				OD#[7:0] - Output Divide#
0x25	00					eserved				-
0x26 0x27	00					D1[7:0] D2[7:0]				_
0x27 0x28	00					eserved				-
0x29	00					D3[7:0]				-1
0x2A	00					D4[7:0]				-
0x2B	00				0	D5[7:0]				1
0x2C	00				R	eserved				-
0x2D	00	Rese	erved	SCR	5[1:0]	SCF	R4[1:0]	SCI	R3[1:0]	SRC5[1:0] - OD5 source 00 - off; 10 - PLLA 01 - PLLC; 11 - PLLB SRC4[1:0] - OD4 source 00 - off; 10 - MHz Reference 01 - PLLC; 11 - 32kHz Reference SRC3[1:0] - OD3 source 00 - off; 10 - 32kHz Reference 01 - MHz Reference; 11 - PLLD

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IDT5P49EE805 VERSACLOCK[®] LOW POWER CLOCK GENERATOR

	Default				E	Bit #				
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x2E	00	Rese	erved	SCF	32[1:0]	SCR1[1:0]		Reserved		SRC2[1:0] - OD2 source 00 - off; 10 - PLLB 01 - 32kHz Reference; 11 - PLLD SRC1[1:0] - OD1 source 00 - off; 10 - PLLC 01 - PLLA; 11 - PLLD
0x2F	01	SCR	0[1:0]			R	eserved			SRC0[1:0] - OD0 source
0x30	FF				Re	eserved				00 - off; 10 - PLLC 01 - PLLB; 11 - PLLD
0x31	00	PDB[6]	Reserved	OE[6B]	OE[6A]		Re	served		PDB[#] - Powerdown OUT#.
0x32	00	OE[5]	OE[4]	OE[3]	Reserved	OE[2]	OE[1]	Reserved	OE[0]	PDB[#]=0, OUT# driven low OE[#] - Output enable OUT#. OE[#]=0,
0x33	00	PDB[5]	PDB[4]	PDB[3]	Reserved	PDB[2]	PDB[1]	Reserved	PDB[0]	OUT# tri-stated. If PDB#=OE#=0, OUT# driven low
0x34	00		1		RE	FA[7:0]	1	1		Configuration1
0x35	00				FB	A[10:3)				(See definitions from Configuration0 above)
0x36	00			Reserved				FBA[2:0)		
0x37	00	Rese	erved	RZ	A[1:0]		IPA[2:0]		REFSELA	
0x38	00				RE	FB[7:0]				
0x39	00				FB	B[10:3]	T			
0x3A	00			MOD[4:0]				FBB[2:0]		
0x3B	00					D[12:5]				
0x3C	00				NC	C[10:3]				
0x3D	00			NSS[4:0]	NO	0(40.5)		NC[2:0]		_
0x3E 0x3F	00 40		Decerved		NS	IPB[2:0]			B[1:0]	_
0x3F 0x40	40		Reserved	Boo	erved	IPD[2.0]		REFSELB	SSENB_B	_
0x40 0x41	00			nes		FC[7:0]		NEFSELD	SSEND_D	_
0x41 0x42	00					C[10:3]				-
0x43	00			Reserved	10	0[10.0]		FBC[2:0]		-
0x44	00				FB	C2[7:0]		. 20[2:0]		-
0x45	00		IPC[2:0]			C[1:0]	Reserved	XDIV	REFSELC	-
0x46	00					FD[7:0]				-
0x47	00				FB	D[10:3]				-
0x48	00			Reserved				FBD[2:0]		
0x49	00	Reserved	RZD	0[1:0]		IPD[2:0]	1	REFS	ELD[1:0]	
0x4A	00				O	D0[7:0]				
0x4B	00				Re	eserved				
0x4C	00					D1[7:0]				
0x4D	00					D2[7:0]				_
0x4E	00					eserved				_
0x4F	00					D3[7:0]				4
0x50	00					D4[7:0]				4
0x51	00					D5[7:0]				4
0x52	00					eserved			2014 01	4
0x53	00		erved		R5[1:0]		R4[1:0]		R3[1:0]	4
0x54	00		erved	SCF	R2[1:0]		R1[1:0]	Re	served	4
0x55	01	SCR	0[1:0]				eserved			4
0x56	FF	DDD(0)	D	05/001		eserved				4
0x57	00	PDB[6]	Reserved	OE[6B]	OE[6A]			served	05/01	4
0x58	00	OE[5]	OE[4]	OE[3]	Reserved	OE[2]	OE[1]	Reserved	OE[0]	4
0x59	00	PDB[5]	PDB[4]	PDB[3]	Reserved	PDB[2]	PDB[1]	Reserved	PDB[0]	

	Default				E	Bit #				
Addr	Register Hex Value	7	6	5	4	3	2	1	0	Description
0x5A	00				RE	FA[7:0]				Configuration2
0x5B	00				FB	A[10:3)				(See definitions from Configuration0 above)
0x5C	00			Reserved				FBA[2:0)		
0x5D	00	Rese	erved	RZA	A[1:0]		IPA[2:0]		REFSELA	
0x5E	00			-1	RE	FB[7:0]				
0x5F	00				FB	B[10:3]				
0x60	00			MOD[4:0]				FBB[2:0]		
0x61	00				MO	D[12:5]				
0x62	00				NC	2[10:3]				
0x63	00			NSS[4:0]				NC[2:0]		
0x64	00				NS	S[12:5]				
0x65	40		Reserved			IPB[2:0]		RZ	B[1:0]	_
0x66	00			Res	erved			REFSELB	SSENB_B	_
0x67	00				RE	FC[7:0]		ł	Ļ	_
0x68	00				FB	C[10:3]				-
0x69	00			Reserved				FBC[2:0]		-
0x6A	00	FBC2[7:0]					-			
0x6B	00		IPC[2:0]		RZC	[1:0]	Reserved	XDIV	REFSELC	-
0x6C	00		REFD[7:0]				-			
0x6D	00				FB	D[10:3]				-
0x6E	00			Reserved				FBD[2:0]		-
0x6F	00	Reserved	RZI	0[1:0]		IPD[2:0]	I	REFS	ELD[1:0]	-
0x70	00				O	00[7:0]				-
0x71	00				Re	served				-
0x72	00				O	01[7:0]				-
0x73	00				O	D2[7:0]				-
0x74	00				Re	served				-
0x75	00				O	03[7:0]				1
0x76	00				O	04[7:0]				1
0x77	00				O	05[7:0]				1
0x78	00				Re	served				1
0x79	00	Rese	erved	SCR	5[1:0]	SCR	4[1:0]	SC	R3[1:0]	1
0x7A	00	Rese	erved	SCR	2[1:0]	SCR	1[1:0]	Re	served	1
0x7B	01	SCR	0[1:0]			Re	eserved	1		1
0x7C	FF				Re	served				1
0x7D	00	PDB[6]	Reserved	OE[6B]	OE[6A]		Re	served		1
0x7E	00	OE[5]	OE[4]	OE[3]	Reserved	OE[2]	OE[1]	Reserved	OE[0]	1
0x7F	00	PDB[5]	PDB[4]	PDB[3]	Reserved	PDB[2]	PDB[1]	Reserved	PDB[0]	1

Marking Diagram (NL28)



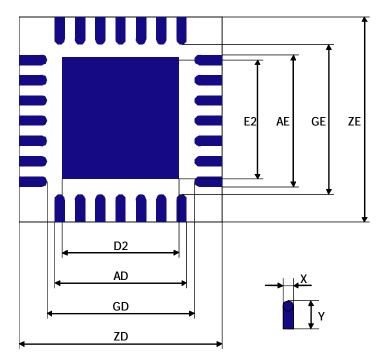
Notes:

- 1. "#" is the lot number.
- 2. YYWW is the last two digits of the year and week that the part was assembled.
- 3. "\$" is the assembly mark code.
- 4. "I" indicates industrial temperature range.
- 5. Bottom marking: country of origin if not USA.

Thermal Characteristics 28-pin QFN

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Thermal Resistance Junction to	θ_{JA}	Still air		48.6		° C/W
Ambient	θ_{JA}	1 m/s air flow		41.7		° C/W
	θ_{JA}	2.5 m/s air flow		37.7		° C/W
Thermal Resistance Junction to Case	θ_{JC}			55.1		° C/W

Landing Pattern

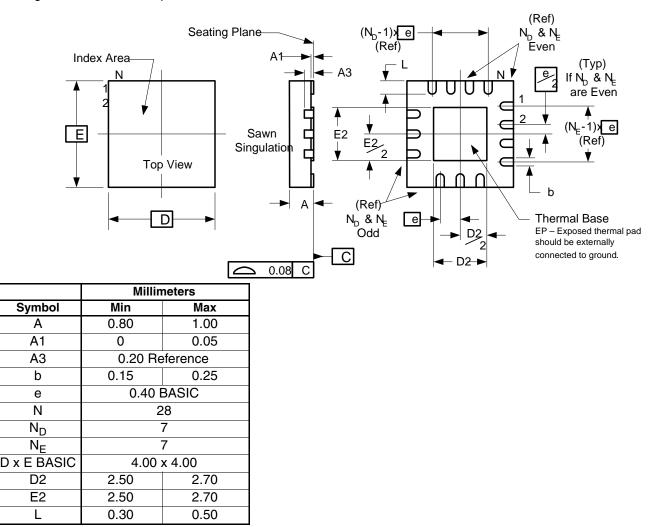


Dimensions	
X(max)	0.25
Yref	0.76
A(max)	2.65
G(min)	2.9
Z(max)	4.41
E2/D2(max)	2.7

Unit : mm

Package Outline and Package Dimensions (28-pin 4mm x 4mm QFN)

Package dimensions are kept current with JEDEC Publication No. 95



Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5P49EE805NDGI	see page 22	Tubes	28pin VFQFPN	-40 to +85° C
5P49EE805NDGI8		Tape and Reel	28pin VFQFPN	-40 to +85° C

"G" after the two-letter package code are the Pb-Free configuration and are RoHS compliant.

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Revision History

Rev.	Originator	Date	Description of Change	
Α	R.Willner	6/02/10	Initial Preliminary Datasheet	
В	R.Willner	9/08/10	Updated thermal pad and dimensions on package drawing. Power ramp sequence.	
С	R. Willner	10/29/10	Typographical changes. Loop filter calculations. Default register bit corrections.	
D	R.Willner	01/19/11	Corrected notes for top-side marking.	
E	R. Willner	04/13/11	 Updated SCLK and SDA pin descriptions Updated DC Electrical Char table for 1.8V LVTTL; added VIH and VIL. Updated "Lock Time/PLL Lock Time from shutdown mode" Typ. and Max. specs in AC Timing Electrical Char table. 	
F	R. Willner	05/04/11	Added Landing Pattern diagram.	
G	R. Willner	0930/11	Updated Power-up/Power-down Sequence notes.	
Н	R. Willner	10/17/11	 Added VDDOx specs to Recommended Operations table Updated Power-up/down Sequence diagrams 	

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